

Product data

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File under Integrated Circuits — ICL03



# CBTD16213

#### **FEATURES**

- 5  $\Omega$  switch connection between two ports
- TTL compatible control input levels
- Designed to be used in level shifting applications
- Package options include plastic shrink small outline (SSOP) and thin shrink small outline (TSSOP)
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA
- ESD protection exceeds 1500 V HBM per JESD22-114A and 1000 V CDM per JESD22-C101

#### DESCRIPTION

The CBTD16213 provides 24 bits of high-speed TTL-compatible bus switching or exchanging. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

A diode to  $V_{CC}$  is integrated into the circuit to allow for level shifting between 5 V inputs and 3.3 V outputs.

The CBTD16213 operates as 24-bit bus switch or a 12-bit bus exchanger, which provides data exchanging between the four signal ports via the data-select (S0–S2) terminals.

The CBTD16213 is characterized for operation from -40 to +85 °C.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25 °C; GND = 0 V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	C <sub>L</sub> = 50 pF; V <sub>CC</sub> = 5 V	0.25	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0 V \text{ or } V_{CC}$	4.5	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$	11.5	pF
Icc	Total supply current	Outputs disabled; $V_{CC}$ = 5.5 V	1.5	mA

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
56-Pin Plastic SSOP	−40 to +85 °C	CBTD16213DL	SOT371-1
56-Pin Plastic TSSOP	−40 to +85 °C	CBTD16213DGG	SOT364-1

Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

#### **FUNCTION TABLE**

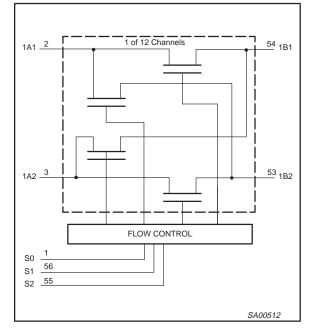
S2	S1	S0	A1	A2	FUNCTION
L	L	L	Z	Z	Disconnect
L	L	Н	B1	Z	A1 = B1
L	Н	L	B2	Z	A1 = B2
L	Н	Н	Z	B1	A2 = B1
Н	L	L	Z	B2	A2 = B2
Н	L	Н	A2 & B2	A1 & B2	A1 = A2 =B2
Н	Н	L	B1	B2	A1 = B1, A2 = B2
Н	Н	Н	B2	B1	A1 = B2, A2 = B1

H = High voltage level

L = Low voltage level

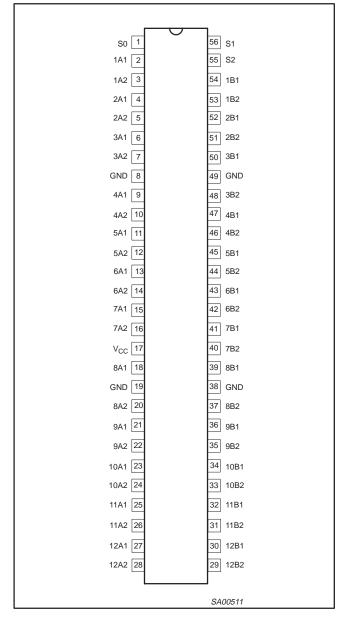
Z = High impedance "off" state

#### LOGIC SYMBOL



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#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 56, 55	S0, S1, S2	Data select
2, 4, 6, 9, 11, 13, 15, 18, 21, 23, 25, 27	1A1–12A1	A1 channel
3, 5, 7, 10, 12, 14, 16, 20, 22, 24, 26, 28	1A2–12A2	A2 channel
54, 52, 50, 47, 45, 43, 41, 39, 36, 34, 32, 30	1B1, 12B1	B1 channel
53, 51, 48, 46, 44, 42, 40, 37, 35, 33, 31, 29	1B2, 12B2	B2 channel
8, 19, 38, 49	GND	Ground (0 V)
17	V <sub>CC</sub>	Positive supply voltage

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### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
I <sub>OUT</sub>	DC output current	output in Low state	128	mA
T <sub>stg</sub>	Storage temperature range		–65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMPOL	SYMBOL PARAMETER	LIM	UNIT	
STMBOL		Min	Max	
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2.0	—	V
V <sub>IL</sub>	Low-level Input voltage	_	0.8	V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

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#### DC ELECTRICAL CHARACTERISTICS

				LIMITS		
SYMBOL	SYMBOL PARAMETER	TEST CONDITIONS	Tamt	T <sub>amb</sub> = −40 to +85 °C		
			Min	Typ <sup>1</sup>	Max	1
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$	—	—	-1.2	V
VP	Output high pass voltage	See Figure 1.	—	—	—	V
		V <sub>CC</sub> = 0 V; V <sub>I</sub> = 5.5 V	—	—	10	
li li	Input leakage current	$V_{CC} = 5.5 \text{ V}; \text{ V}_{I} = \text{GND or } 5.5 \text{ V}$	—	—	±1	μA
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 5.5 \text{ V}; I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$	—	—	1.5	mA
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5 V, one input at 2.7 V, other inputs at V <sub>CC</sub> or GND	-	_	2.5	mA
Cl	Control pins	V <sub>I</sub> = 3 V or 0 V		4.5	—	pF
	Port off capacitance B port		—	11.5	—	pF
C <sub>IO(OFF)</sub>	Port off capacitance A port	$V_{O} = 3 V \text{ or } 0 V; S0, S1, \text{ or } S2 = V_{CC}$	—	11.5	—	pF
		$V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 64 \text{ mA}$		4	8	
	A to B or B to A	V <sub>CC</sub> = 4.5 V; V <sub>1</sub> = 0 V; I <sub>I</sub> = 30 mA	—	4	8	1
_ 3		V <sub>CC</sub> = 4.5 V; V <sub>1</sub> = 2.4 V; I <sub>1</sub> = 15 mA	-	15	20	1
r <sub>on</sub> 3		$V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 64 \text{ mA}$	—	8	10	Ω
	A1 to A2	$V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 30 \text{ mA}$	<b>—</b>	8	10	1
		V <sub>CC</sub> = 4.5 V; V <sub>1</sub> = 2.4 V; I <sub>1</sub> = 15 mA	—	24	30	1

NOTES:

1. All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_{amb} = 25 \text{ °C}$ 2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than  $V_{CC}$  or GND. 3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

### **AC CHARACTERISTICS**

 $GND = 0 V; t_{R}; C_{L} = 50 pF$ 

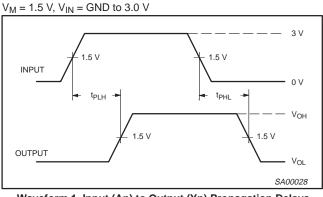
SYMBOL	PARAMETER	FROM (INPUT)	то	$V_{CC}$ = +5.0 V ±0.5 V		UNIT	
STMBOL	PARAMETER		(OUTPUT)		Max	UNIT	
•	A or B	A or B	B or A	—	0.25	ns	
t <sub>pd</sub>	Propagation delay <sup>1</sup>	A1	A2	—	0.5	ns	
	Output enable time	Output enable time S	S	A or B	3.2	9.6	ns
t <sub>en</sub>	to High and Low level	S0	A2 and B2	1.8	8.2	ns	
	Output disable time	S S0	A or B	2.1	8.5	ns	
t <sub>dis</sub>	from High and Low level		A2 and B2	1.4	7.5	ns	

NOTES:

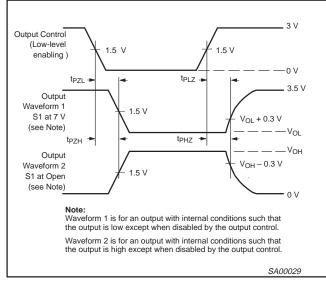
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

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#### AC WAVEFORMS

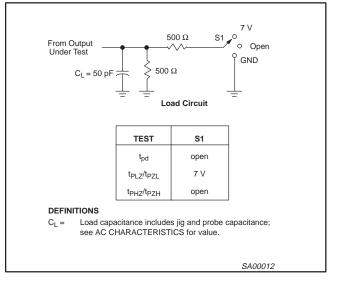


Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

#### **TEST CIRCUIT AND WAVEFORMS**



# CBTD16213

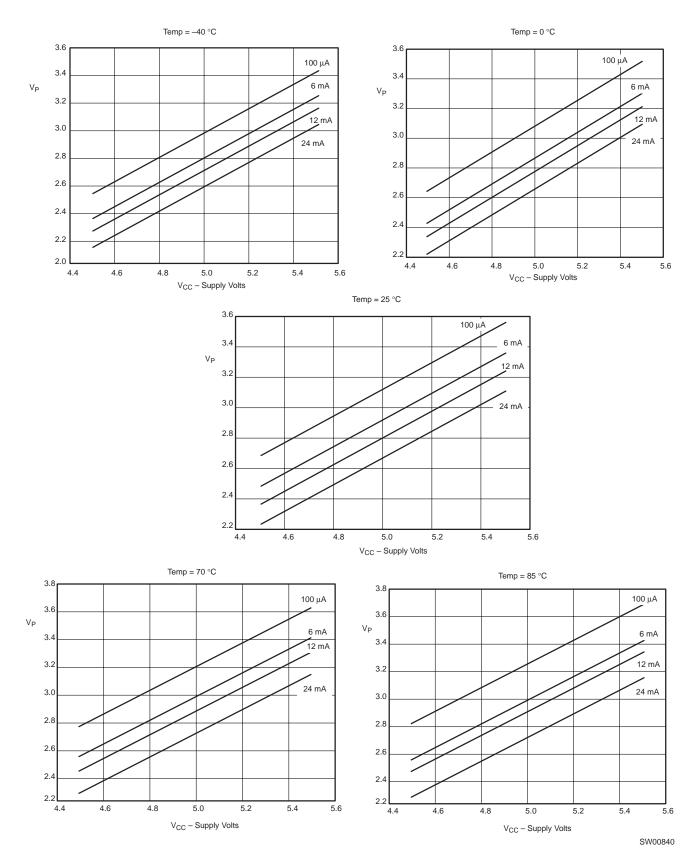
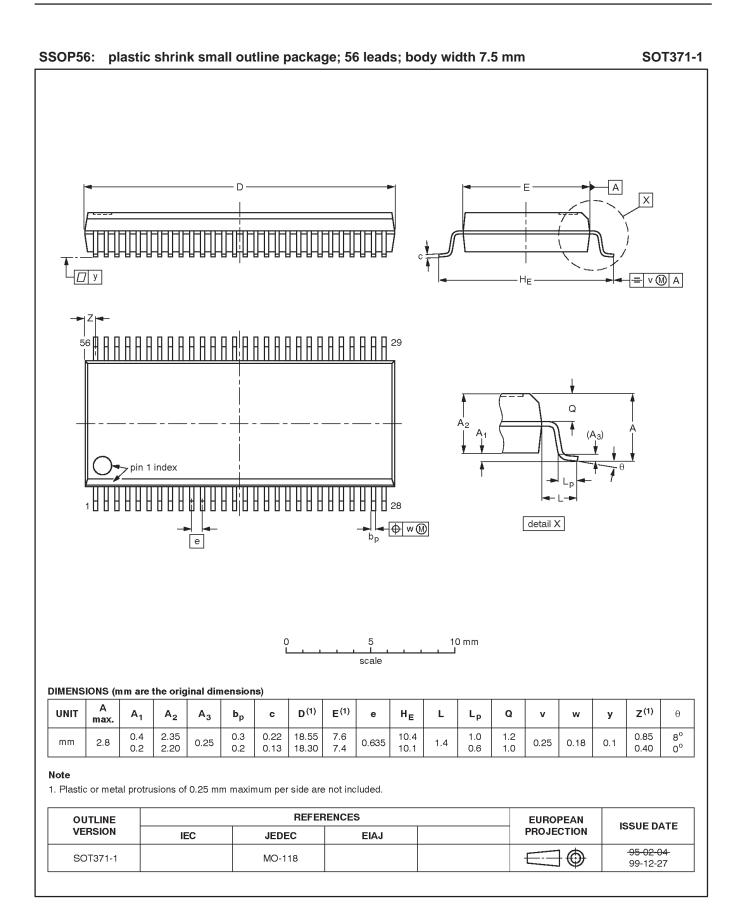


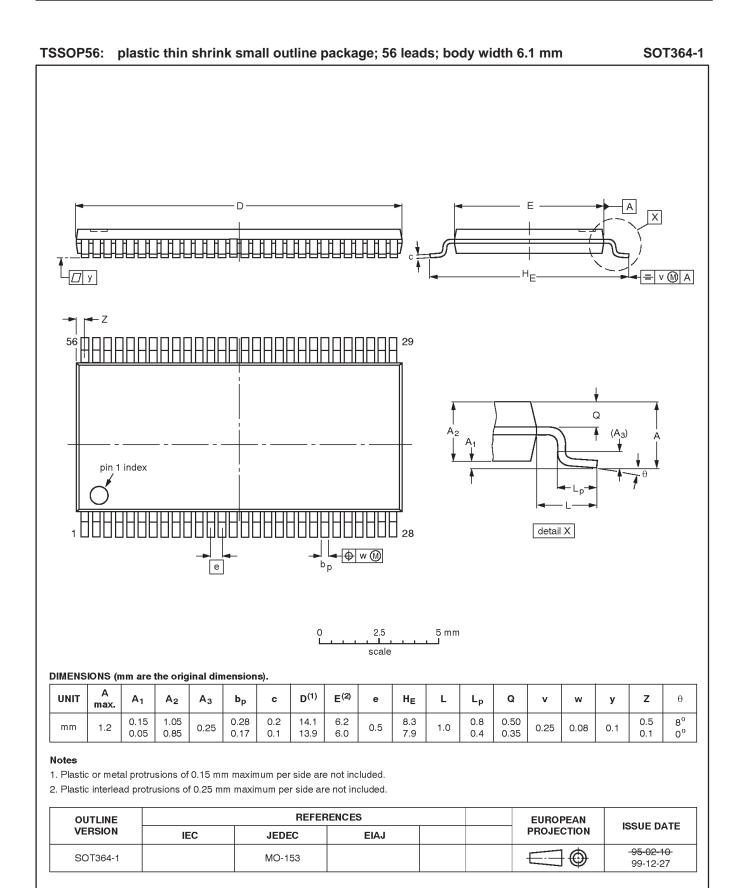
Figure 1. Typical characteristics

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Product data



#### Data sheet status

Data sheet status <sup>[1]</sup>	Product status <sup>[2]</sup>	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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